



# Thermoelectric properties of SnSe composite with MoSe<sub>2</sub>

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## 1. Introduction

$$ZT = \frac{\alpha^2 \sigma T}{\kappa}$$

High  $PF$   
large  $\alpha$

- Quantum confinement
- Electron energy filtering
- Resonance levels

high  $\sigma$

- Modulation doping
- Crystallite alignment
- Composite engineering

Low  $\kappa$

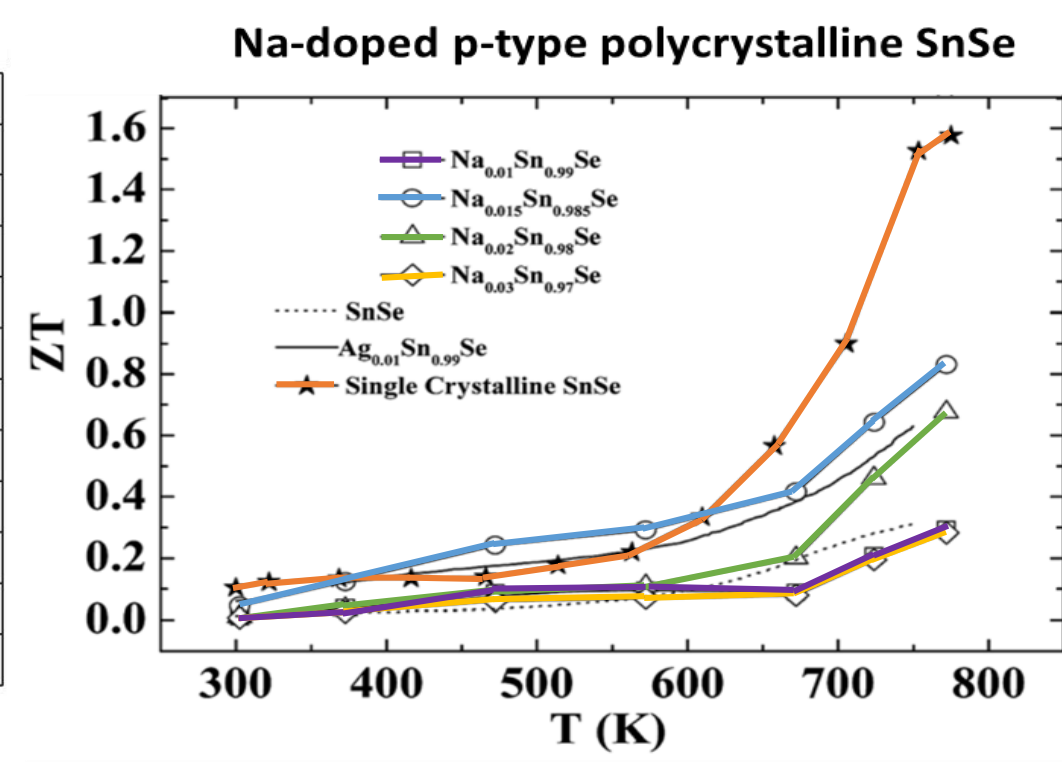
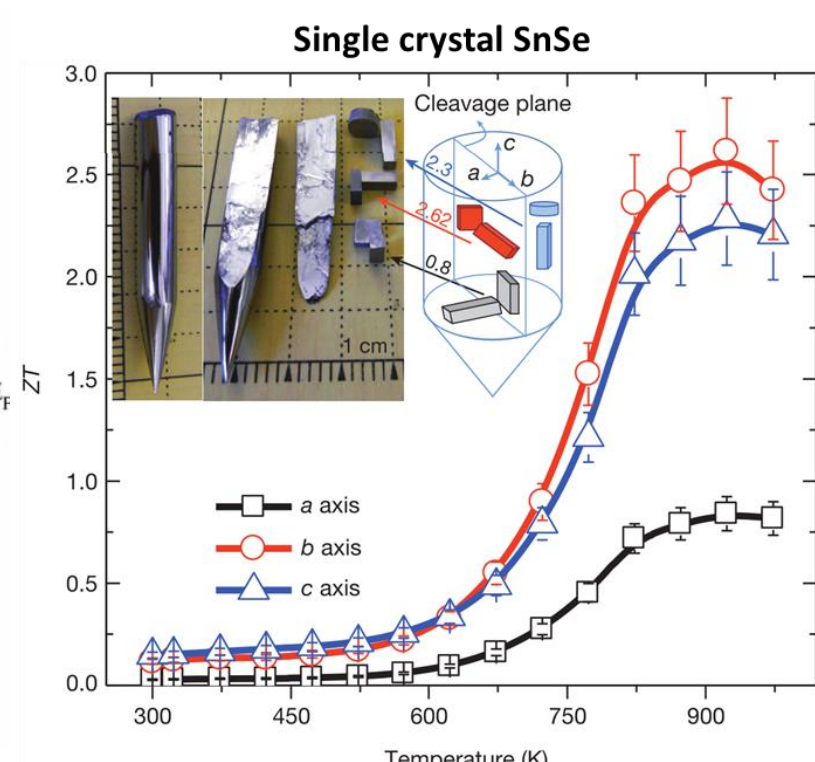
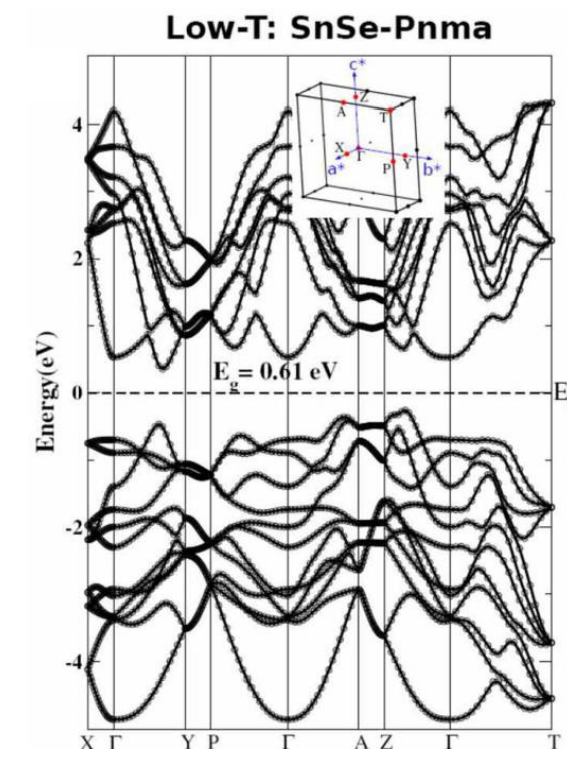
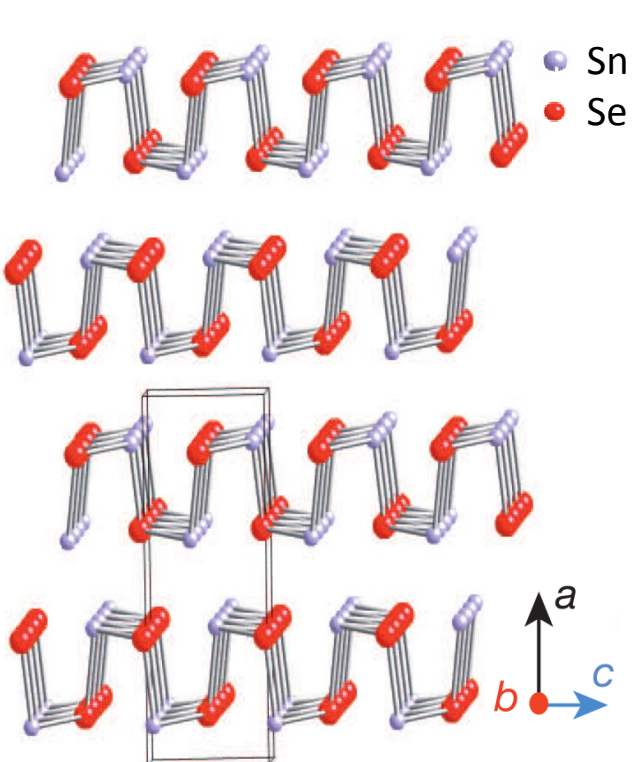
- PGEC approach
- Nanostructuring techniques
- All-scale hierarchical structuring
- Intrinsic low  $\kappa$
- Zintl phases
- Sulphur-based compound

High  $ZT$

Arash Mehdizadeh Dehkordi, *Mater. Sci. Eng. R* 97, 2015, 1–22

Eyob K. Chere, *J. Mater. Chem. A*, 2016,4,1848-1854

Crystal structure & electronic band structure of SnSe



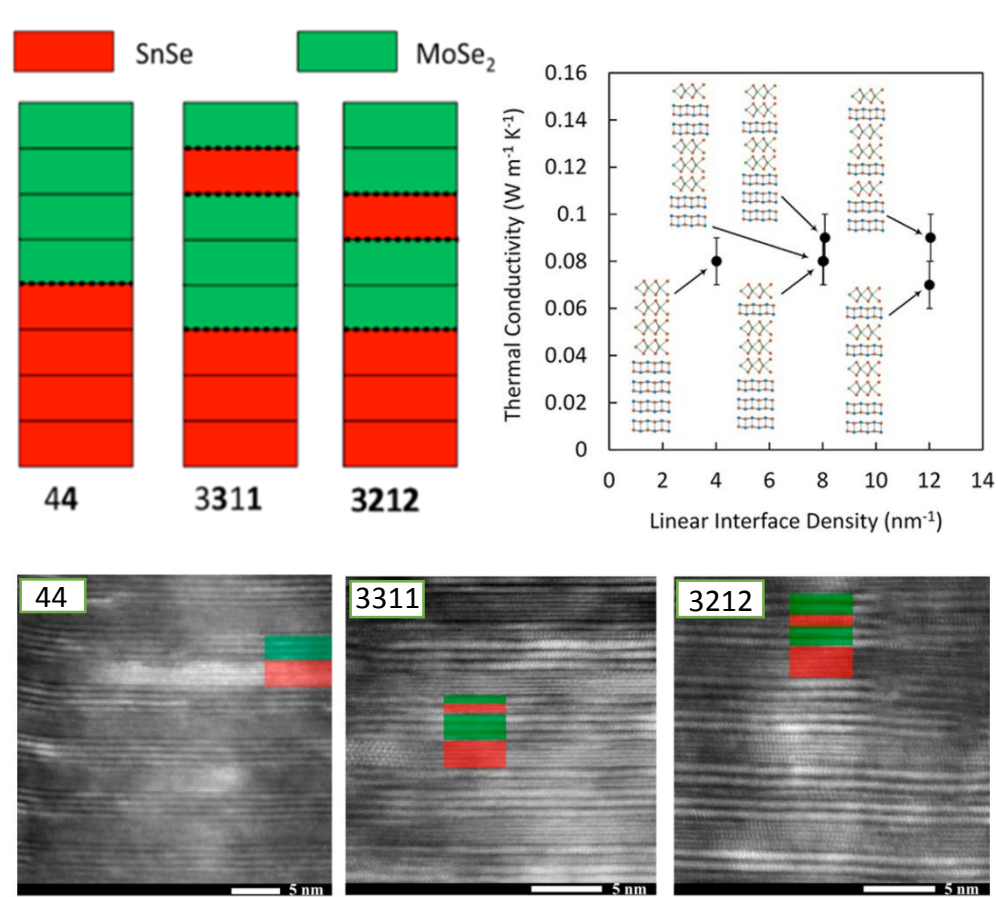
Li-Dong Zhao, *Nature* 13184,373-377(2014)

Li-Dong Zhao, *Nature* 13184,373-377(2014)

Eyob K. Chere, *J. Mater. Chem. A*, 2016,4,1848-1854

## 2. Motivations

SnSe and MoSe<sub>2</sub> Layered structural isomers



Noel S. Gunning, *J. Am. Chem. Soc.* 2015,137,8803-8809

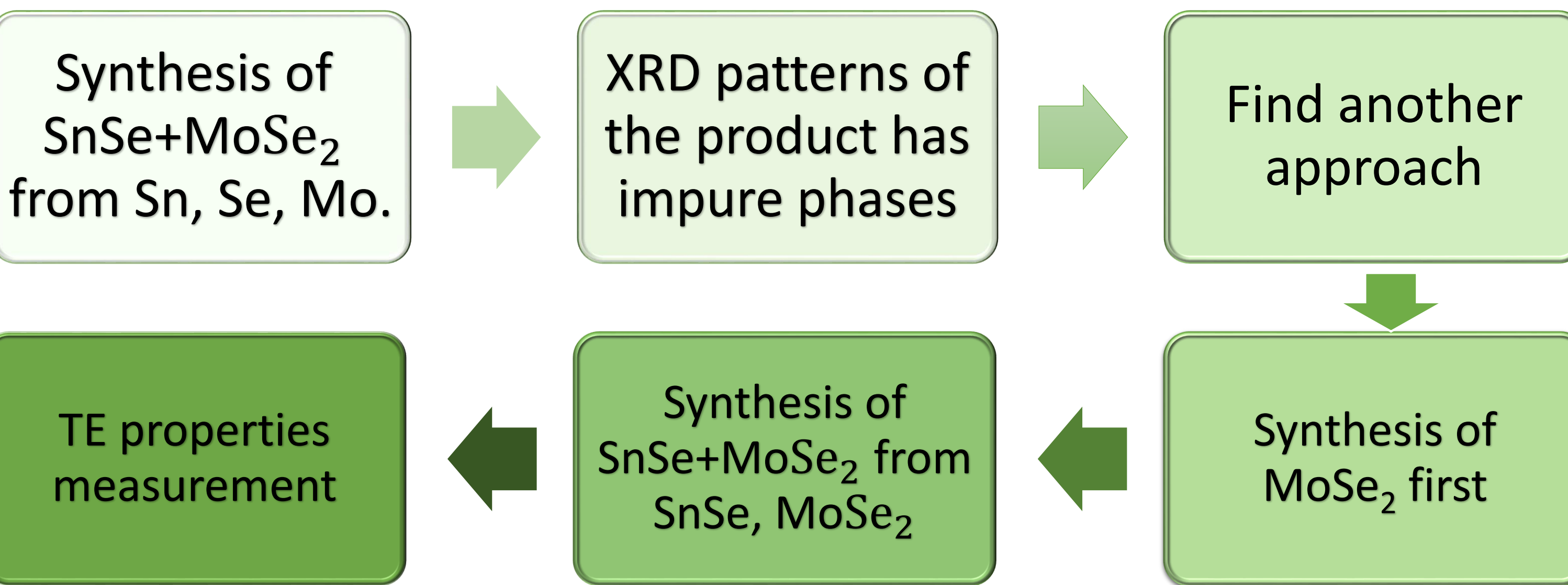
- Large cross-plane thermal resistance created by SnSe–MoSe<sub>2</sub> and MoSe<sub>2</sub>–MoSe<sub>2</sub> turbostratically disordered van der Waals interfaces



This work

- Search for low thermal conductivity in the bulk SnSe composite with MoSe<sub>2</sub>, by conventional solid-state reaction method and densified by spark plasma sintering

## 3. Experimental procedures



TE properties measurement

Seebeck coefficient  $\alpha$ : Zem-3(323K~773K)

Electrical conductivity  $\sigma$ : Zem-3(323K~773K)

Thermal diffusivity  $D$ : Laser flash method(323K~773K)

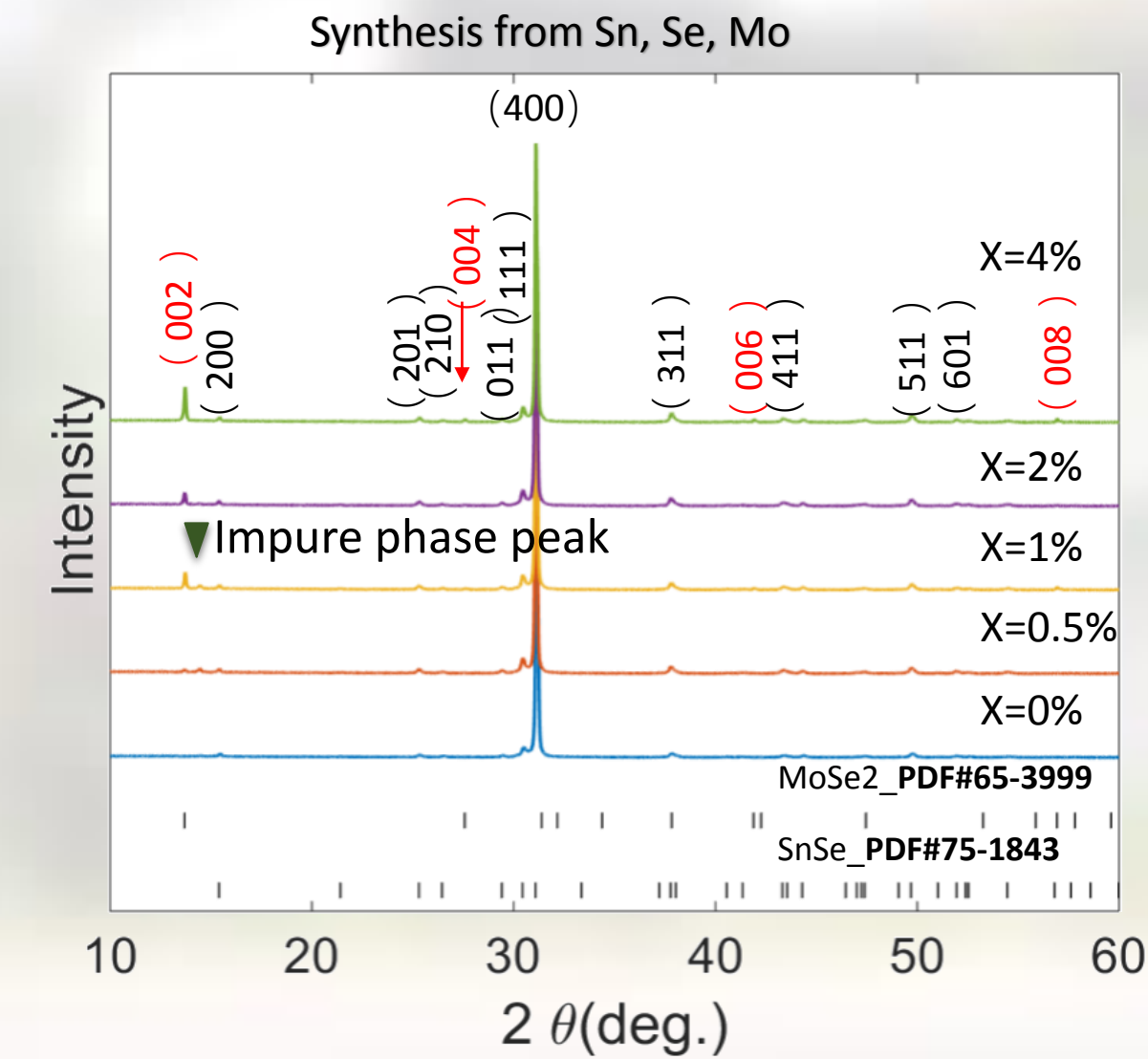
$$\kappa = D \times C_p \times \rho (C_p: \text{specific heat}; \rho: \text{density})$$

Phase composition component analysis

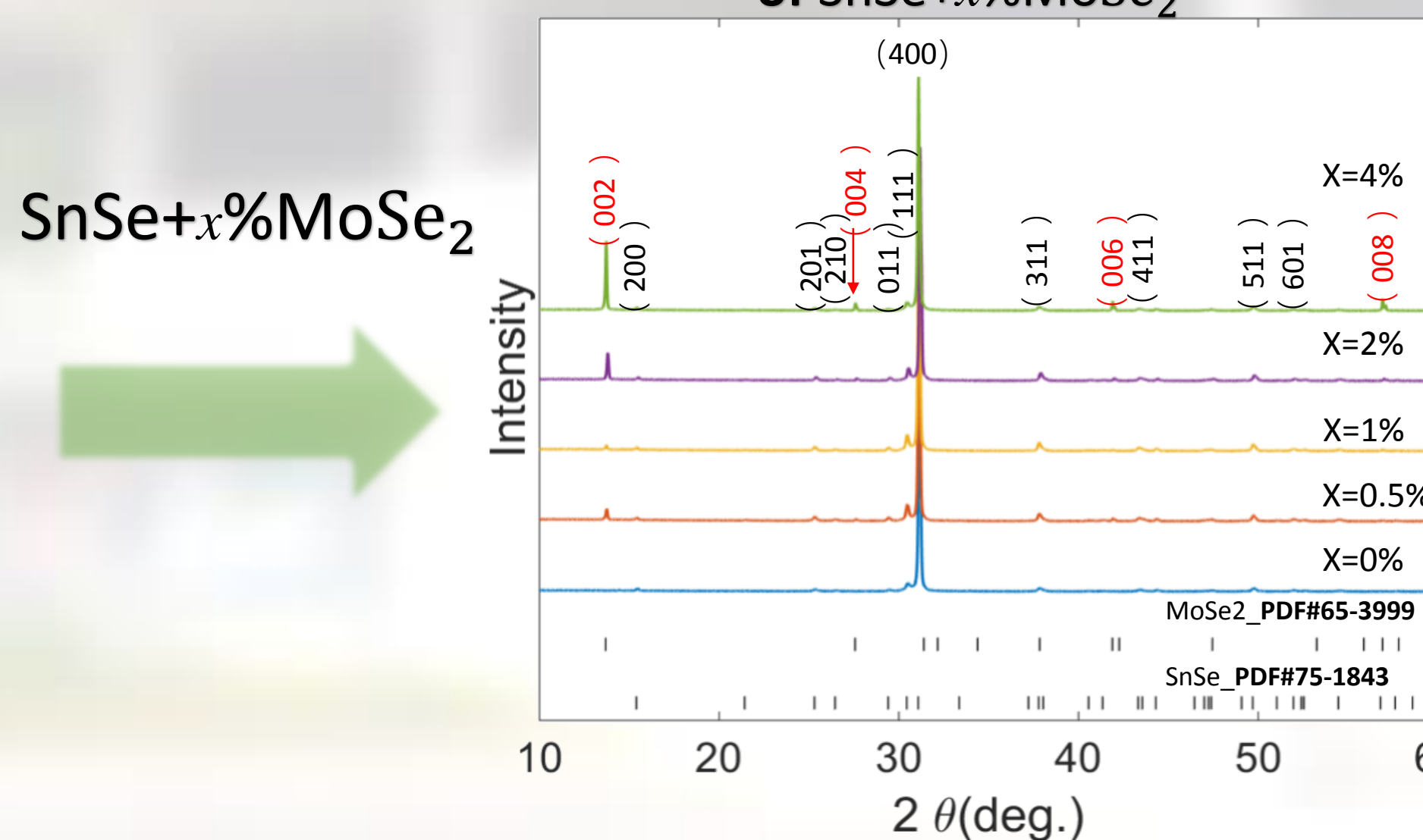
XRD, SEM, and EDX

## 4. Results

Powder XRD-pattern of SnSe+x%MoSe<sub>2</sub>



Powder XRD-pattern of SnSe+x%MoSe<sub>2</sub>



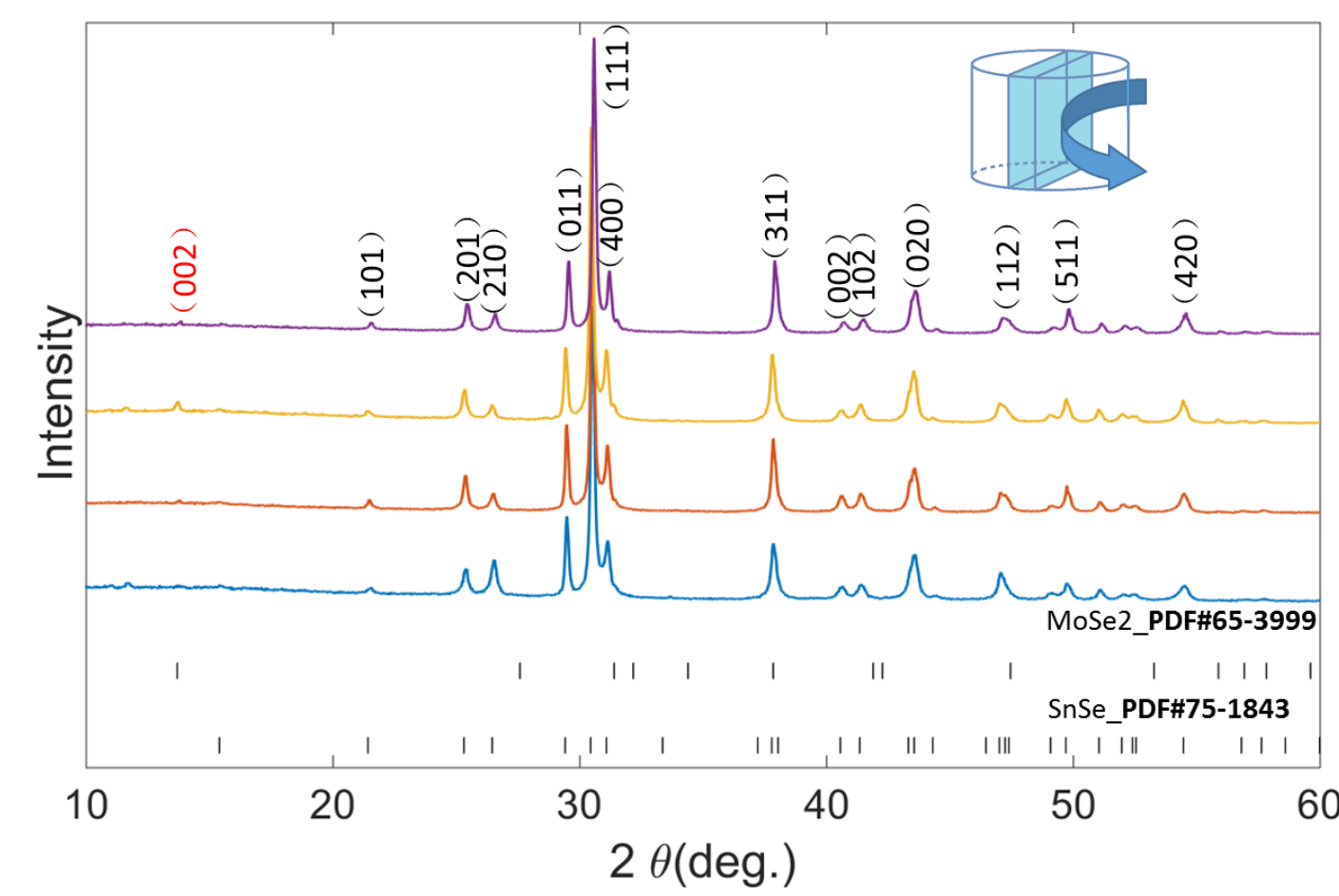
## 5. Conclusions & Future plans

- SnSe+ x% MoSe<sub>2</sub> (x = 0.5, 1.0, 1.5 and 2.0) composites are prepared by were prepared by conventional solid-state reaction method followed by SPS;
- SEM images indicated that microstructure variable with the amount of MoSe<sub>2</sub>;
- ZT values haven't changed significantly, and ZT<sub>max</sub> ~ 0.38 is obtained at 773K for x = 0.10.

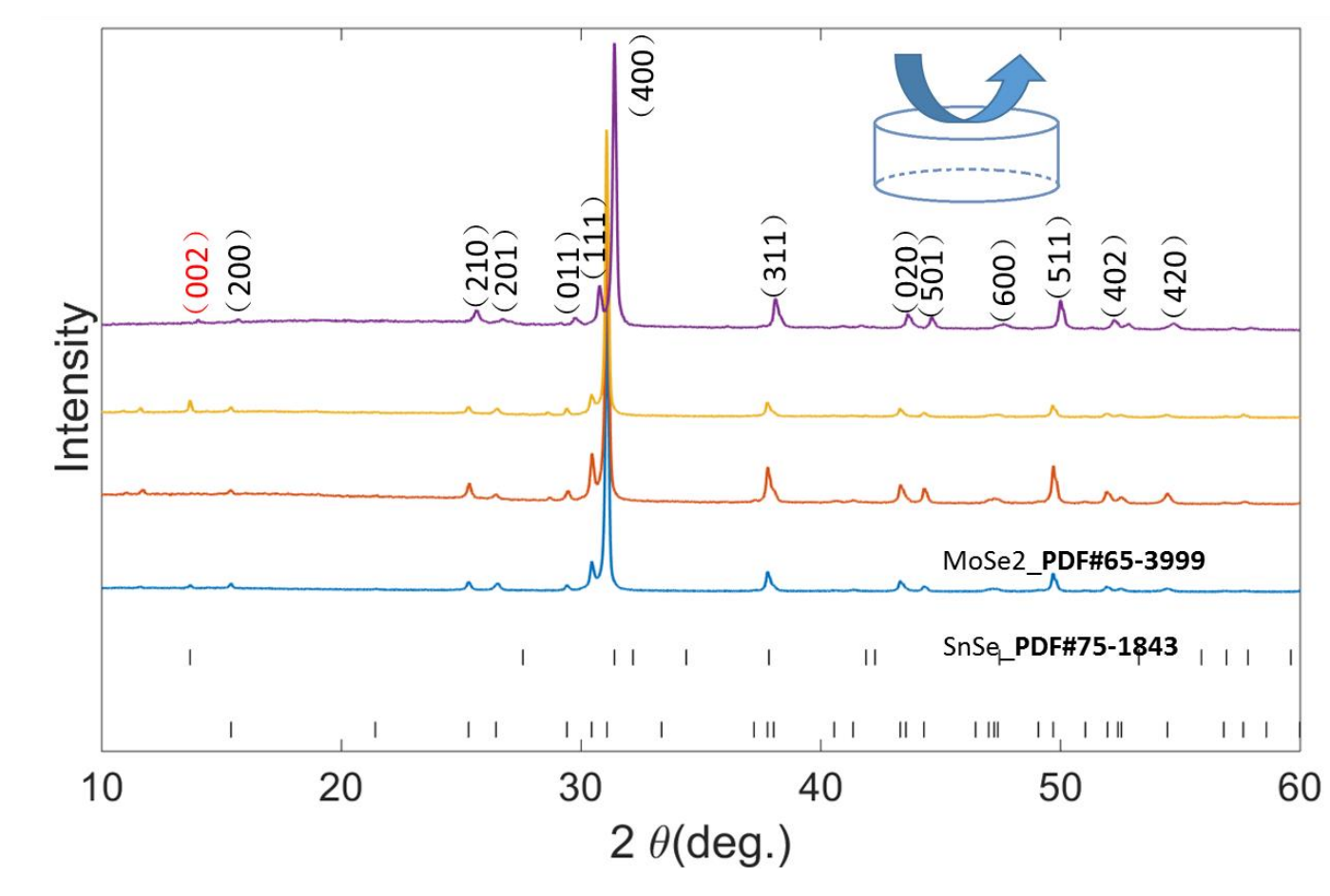
Future plans

For x = 1.0%, precipitated phase was observed in SEM which may lead to the exceptional behavior in transport properties. This encourage us to further investigate the formation mechanism of the precipitated phase.

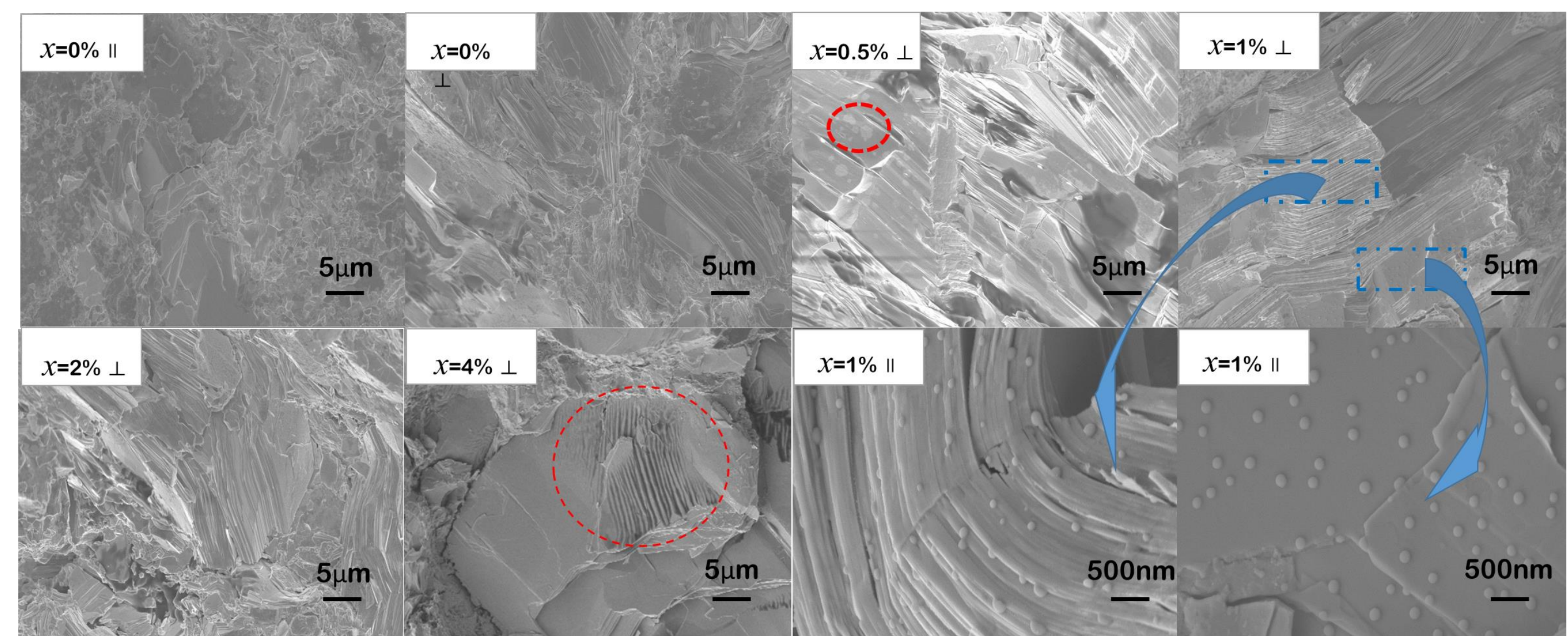
Bulk XRD-pattern  $\perp$



Bulk XRD-pattern  $\parallel$



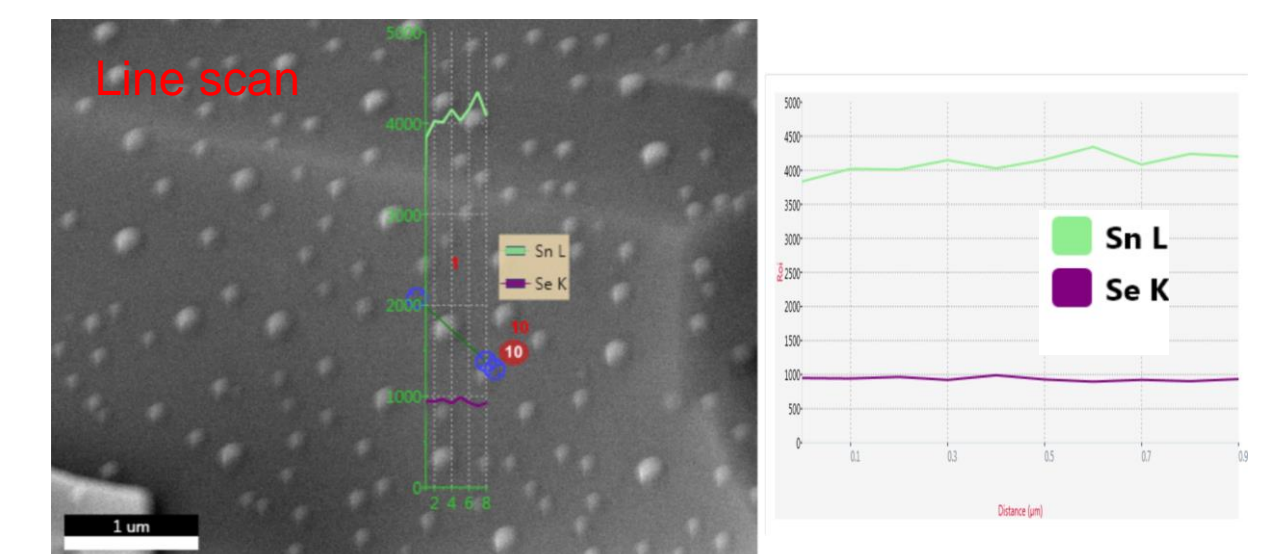
SEM images of SnSe+x%MoSe<sub>2</sub>



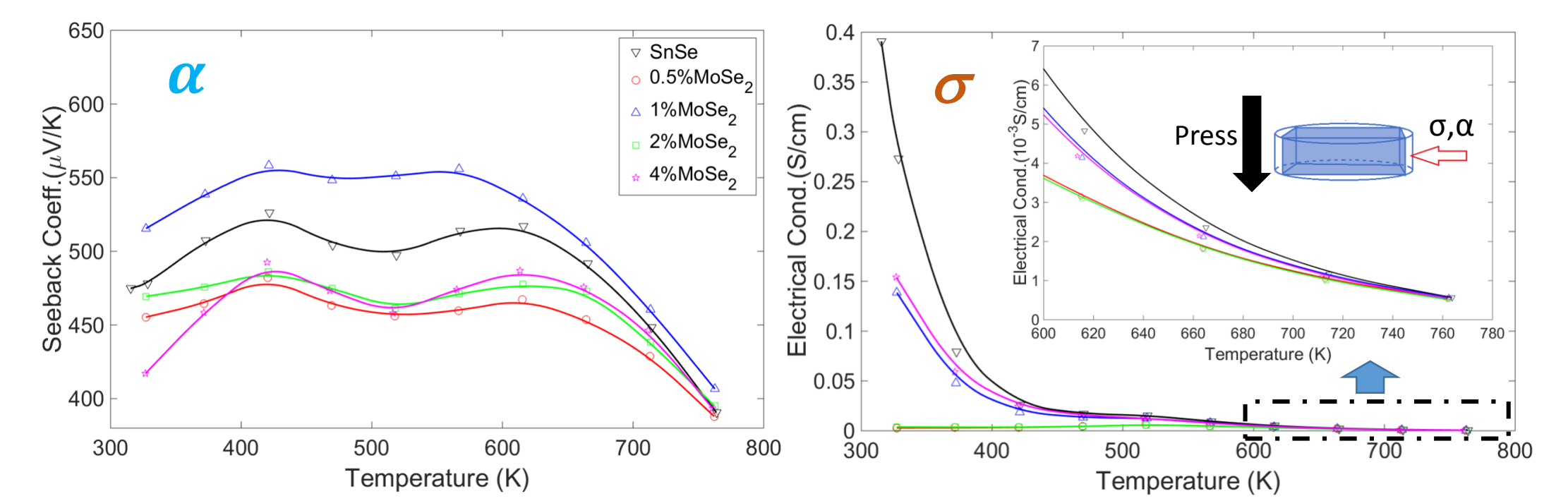
SEM: microstructure variable with the amount of MoSe<sub>2</sub> specially in  $\perp$  direction

EDX results of SnSe+1.0%MoSe<sub>2</sub>

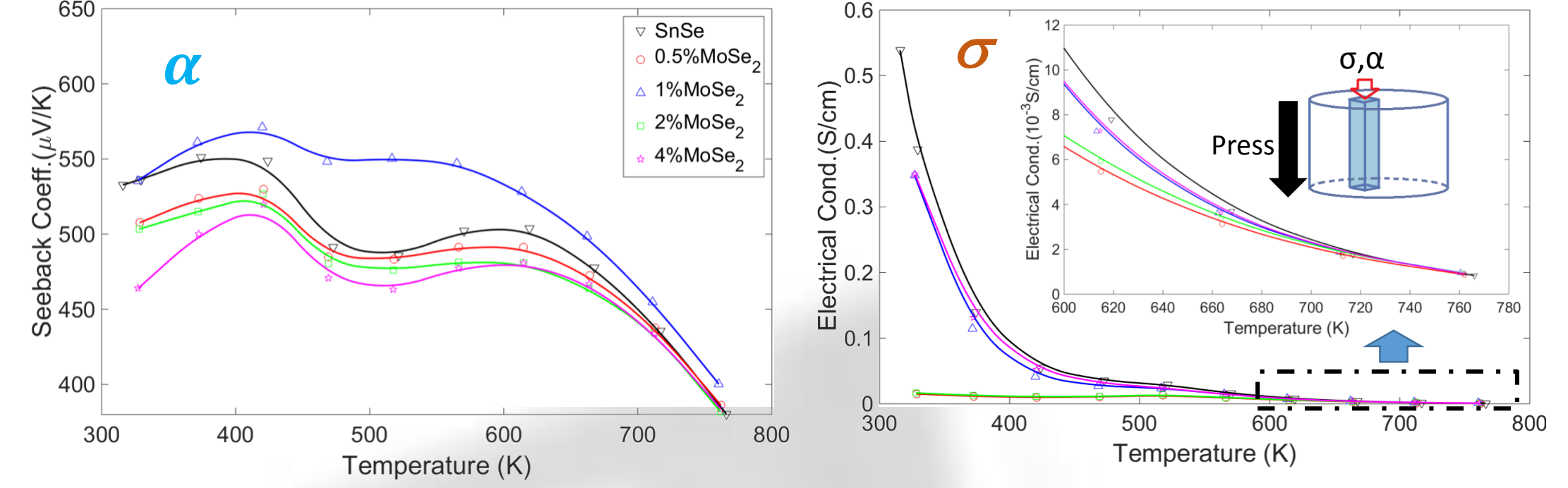
Precipitate phase consist of only Sn and Se elements indicated the same composition of main phase



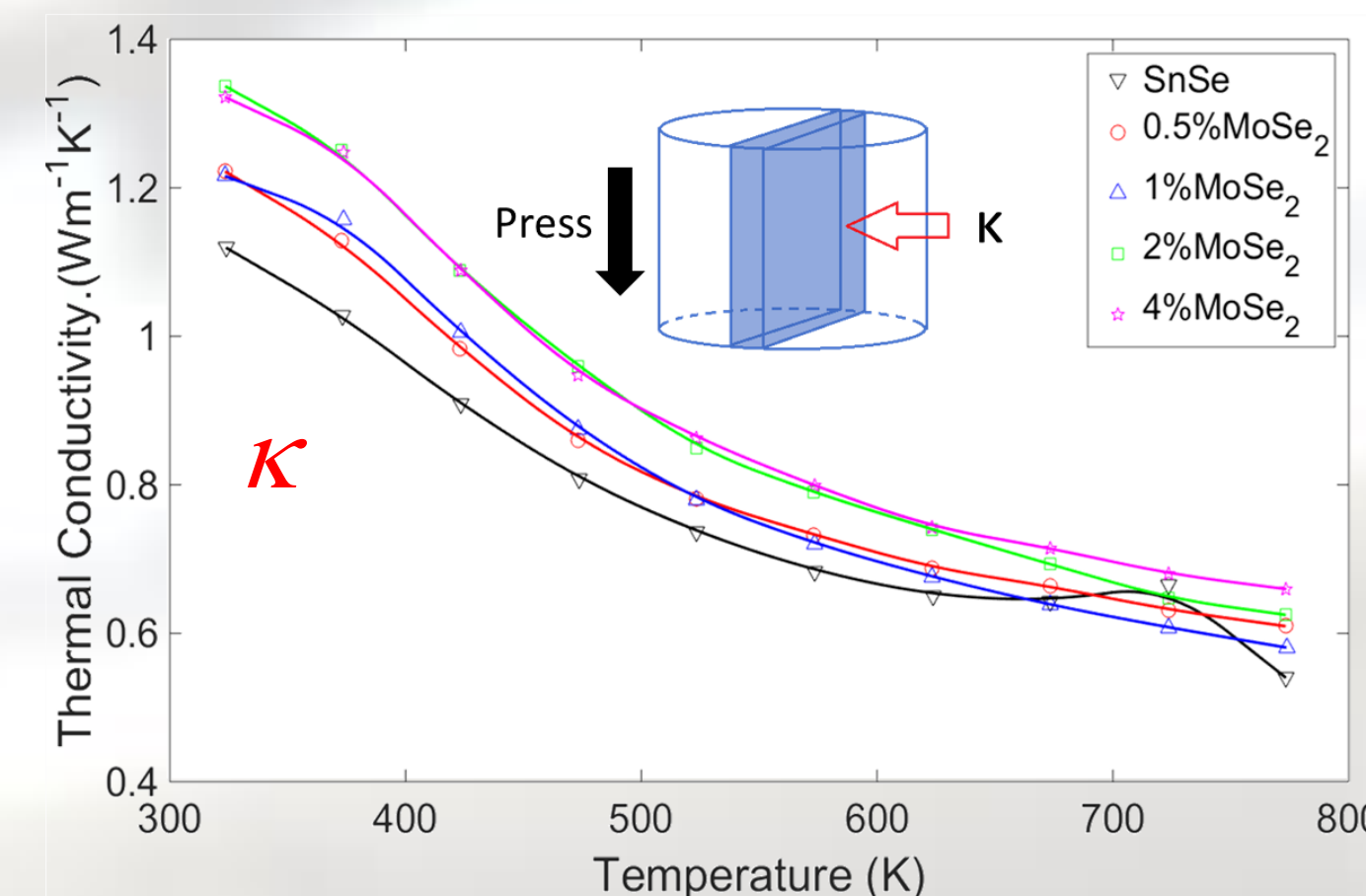
Transport properties  $\perp$



Transport properties  $\parallel$



Thermal properties  $\perp$



ZT values  $\perp$

